Diode Semiconductor Device - Page 1 of 1



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Inclosure Mate	rial:
Metal	
Overall Length	1:
Between 6.85 r	nillimeters and 7.49 millimeters
Terminal Leng	th:
0.51 millimeters	3
Overall Height	:
Between 2.19 r	nillimeters and 2.38 millimeters
Overall Width:	
Between 6.35 r	nillimeters and 6.73 millimeters
Function For W	Vhich Designed:
Rectifier	
Joint Electron	ic Device Engineering Council/jedec/case Outline Designation:
To-252	
Mounting Meth	nod:
Terminal	
Features Prov	ided:
Hermetically se	aled case and electrostatic sensitive
Semiconducto	r Material:
Silicon	
Voltage Rating	In Volts Per Characteristic:
100.0 repetitive	e peak reverse voltage
Current Rating	Per Characteristic:
3.30 amperes f	orward current, average absolute
Terminal Type	And Quantity:
2 uninsulated w	vire lead
Shelf Life:	
N/a	
Unit Of Measu	re:
Demilitarizatio	n:
No	
Fiig:	
A110a0	